

Photovoltaic Performance of FAPbI₃ Perovskite Is Hampered by Intrinsic Quantum Confinement

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Cite This: *ACS Energy Lett.* 2023, 8, 2543–2551



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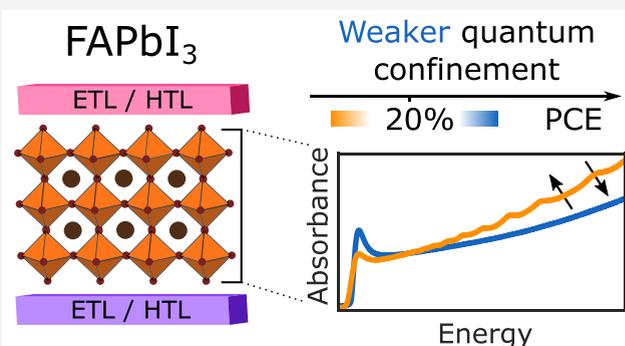
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Supporting Information

ABSTRACT: Formamidinium lead triiodide (FAPbI₃) is a promising perovskite for single-junction solar cells. However, FAPbI₃ is metastable at room temperature and can cause intrinsic quantum confinement effects apparent through a series of above-bandgap absorption peaks. Here, we explore three common solution-based film-fabrication methods, neat *N,N*-dimethylformamide (DMF)–dimethyl sulfoxide (DMSO) solvent, DMF–DMSO with methylammonium chloride, and a sequential deposition approach. The latter two offer enhanced nucleation and crystallization control and suppress such quantum confinement effects. We show that elimination of these absorption features yields increased power conversion efficiencies (PCEs) and short-circuit currents, suggesting that quantum confinement hinders charge extraction.

A meta-analysis of literature reports, covering 244 articles and 825 photovoltaic devices incorporating FAPbI₃ films corroborates our findings, indicating that PCEs rarely exceed a 20% threshold when such absorption features are present. Accordingly, ensuring the absence of these absorption features should be the first assessment when designing fabrication approaches for high-efficiency FAPbI₃ solar cells.



Metal halide perovskites (MHPs) have experienced tremendous progress in the past decade, reflected by a substantial improvement in the power conversion efficiency (PCE) of perovskite solar cells from a low 3.8%¹ to values now regularly exceeding 25%^{2,3} in just over a decade. These materials owe their excellent optoelectronic properties and photovoltaic (PV) performance to benign defect chemistry,^{4–10} high charge-carrier mobilities,¹¹ long diffusion lengths,^{12,13} low exciton binding energies,¹⁴ and broadly tunable absorption spectra.¹⁵ While many promising MHP compositions have been explored as active layers in photovoltaic devices, those centered around formamidinium lead triiodide (FAPbI₃) have arguably emerged among the most promising,¹⁶ currently holding the single-junction MHP device efficiency record with a certified power conversion efficiency (PCE) of 25.7%^{2,3,17} and being one of the most investigated compositions according to a recent literature survey by Jacobsson et al.¹⁸ The success of FAPbI₃ partly derives from its near-optimal bandgap¹⁶ for single-junction cells¹⁹ and its enhanced stability under elevated temperatures compared to other commonly explored hybrid MHPs based on methylammonium, such as MAPbI₃.^{20–22} In addition, FAPbI₃

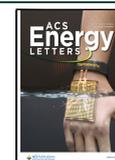
importantly offers simplicity of stoichiometry compared with alloyed MHPs containing multi A-site cations or mixed halides, which enhances its resistance against compositional dealloying and the formation of compositional inhomogeneities that can adversely affect performance.^{23–27}

However, one aspect of FAPbI₃ requiring careful control is structural stability. At room temperature, the desired perovskite α -phase is only metastable and easily deteriorates into a thermodynamically favorable, yellow, nonperovskite 2H (δ)-phase that is not particularly photoactive.²⁸ Early work demonstrated that partial substitution of FA with Cs with as little as 5%^{28–33} is sufficient to eliminate traces of δ -phase presence in XRD patterns,^{34,35} but such a degree of A-site alloying shifts the band gap to higher energies³² and has been

Received: March 28, 2023

Accepted: May 4, 2023

Published: May 10, 2023



shown to introduce undesirable compositional inhomogeneities.^{36,37} Recently, a plethora of fabrication methods and optimization approaches have therefore been developed to attain and stabilize the “unalloyed” perovskite α -phase of FAPbI₃.^{11,20,21,32,38–44} These alterations to earlier fabrication methods¹⁶ vary from introducing pre- and postannealing steps and additive treatments^{45,46} to more elaborate stoichiometric engineering techniques,^{40,47,48} vapor codeposition,⁴³ and more recently templating and sequential deposition strategies via solution⁴⁹ or vapor deposition⁴⁴ routes, yielding significant advances in stability and performance.

In addition, one peculiarity specific to FAPbI₃ is its propensity to exhibit intrinsic quantum confinement, which has been attributed to the formation of intrinsic nanostructured domains on the length scale of ~ 10 nm in subvolumes of nominally bulk films.^{50,51} Evidence for these features has been derived from the presence of peculiar above-bandgap peaks that are superimposed on bulk-like absorption spectra and that had gone mostly unnoticed and unexplained^{16,32,52,53} until recently.^{50,51} Analysis of these absorption peak features has directly pointed toward the presence of electronic quantum confinement, and while these structures have not been imaged directly to date, it has been suggested that they could derive from the presence of thin slices of α -phase FAPbI₃ intrinsically self-assembling to form superlattices or quantum wells surrounded by regions acting as energetic barriers,⁵⁰ potentially in an attempt to alleviate some of the experienced strain in the lattice.⁵⁴ Such energy barriers may constitute inclusions of the δ - or alternative secondary phases forming thin layers undetectable in XRD patterns, with a relatively high Cs content of $\geq 40\%$ recently having been found to eliminate any traces of such quantum confinement.⁵¹ It should be expected that any form of quantum confinement experienced by charge carriers even in small subvolumes of the absorber layers hinders the unobstructed passage of the photocurrent throughout a solar cell. Surprisingly though, the relationship between the presence of intrinsic quantum confinement features in the absorption spectra of FAPbI₃ and the performance of photovoltaic devices based on these layers has not yet been examined. Such an investigation is particularly urgent in the context of the myriad of fabrication protocols developed for FAPbI₃, which currently focus relatively narrowly on elimination of δ -phase features in XRD patterns that has, however, been shown to be an inaccurate indicator^{50,51} of whether or not intrinsic quantum confinement will be present.

In this letter, we unravel the extent to which intrinsic quantum confinement in FAPbI₃ affects solar cell performance. We contrast evidence of quantum confinement gathered from features in thin-film optical absorption spectra with photovoltaic performance parameters extracted from devices incorporating the same absorber layers. We directly examine three different fabrication routes as exemplifiers, but to ensure that our findings are generally applicable, we also perform a comprehensive meta-analysis of literature reports across the field. While our three experimentally fabricated FAPbI₃ films appear to be compositionally identical, the materials have experienced different crystallization dynamics and therefore are likely to possess different strain environments. Using structural and optical analysis, we show that such variations strongly affect the extent to which the FAPbI₃ films exhibit domains experiencing intrinsic quantum confinement. We demonstrate a clear positive correlation between the photovoltaic power

conversion efficiency and steady-state short-circuit current J_{SC} values of corresponding devices with the absence of peak features in the absorption spectrum, revealing that intrinsic quantum confinement in FAPbI₃ hinders photovoltaic performance. In our meta-analysis of literature reports, we examine photovoltaic PCE data reported for 825 devices with three-dimensional stoichiometric FAPbI₃ films as absorber layers across 244 literature articles and categorize these according to whether or not intrinsic quantum confinement is evident in thin-film absorption spectra reported alongside. We discover that elimination of these features is highly correlated with the recent performance gains of FAPbI₃ solar cells. Importantly, we find that devices incorporating films that possess such features rarely exceed PCE value of 20%, suggesting that such intrinsically formed confinement domains provide inherent barriers that become clearly apparent once all other detriments have been eliminated. Accordingly, we propose that checking for the absence of these absorption features should be the first point of investigation when gauging the effectiveness of a new fabrication approach for FAPbI₃ thin films designed to act as photoabsorber layers in high-efficiency solar cells.

We focus our experimental investigation on stoichiometric FAPbI₃ films fabricated using three different solution-based processing routes. The first set of FAPbI₃ films (labeled “DMF-DMSO”) were fabricated using the standard deposition method based on neat DMF-DMSO (DMF, *N,N*-dimethylformamide; DMSO, dimethyl sulfoxide) solvent utilizing “antisolvent quenching” without any additives aimed at stabilizing the α -phase or slowing down the crystallization process.^{16,20,21,42} The second set of FAPbI₃ films (labeled “MAcI route”) resulted from DMF-DMSO solution-casting involving the use of excess MAcI (methylammonium chloride) as an additive to induce an intermediate phase which is easily transformed to the neat α -phase.⁵⁵ MAcI thus effectively directs the crystallization process by providing an alternative crystallization pathway and improving by improving the grain size and crystallographic purity of the fabricated film.²⁰ Use of this additive has frequently been reported in the literature to stabilize the α -phase and consistently results in devices with enhanced PV performances, with fabrication methods now optimized to ensure the predominant exclusion of MA⁺ and Cl⁻ ions from the crystal structure in order to yield near-stoichiometric FAPbI₃ films.^{20,21,42,55–57} The third set of FAPbI₃ films (labeled “Sequential”) was fabricated through a sequential deposition method based on work by Noel et al.⁵⁸ whereby first a 2D perovskite material is deposited, thermally treated, and subsequently converted to the α -FAPbI₃ phase by means of an alcoholic solution of formamidinium iodide, analogous to archetypical two-step processing methods of halide perovskites.^{49,59} Such sequential deposition allows for careful curation of a solid-state intermediate phase and initiates the formation of high-quality FAPbI₃ in its black perovskite α -phase, suppressing inclusions of unintended structures.^{42,49,58–60} Careful control over the emerging crystal structure can therefore be attained, which provides the additional opportunity to investigate films fabricated through a significantly more controlled route compared to those of the FAPbI₃ films fabricated from neat DMF-DMSO solvent or even MAcI-additive routes.⁵⁸ Further details about each individual fabrication method are presented in the [Supporting Information \(SI\)](#).

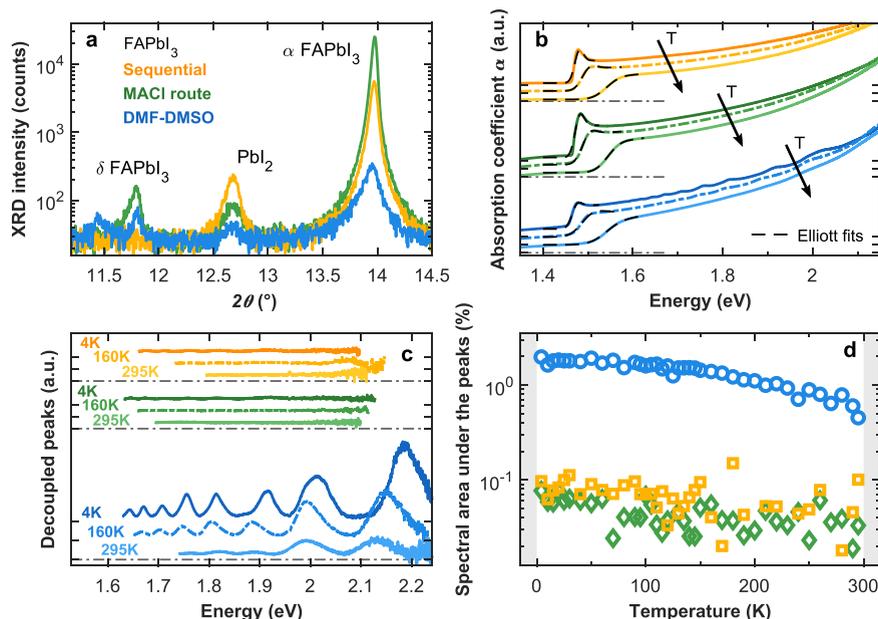


Figure 1. Structural and optical properties of stoichiometric FAPbI₃ films made from different fabrication methods. (a) Excerpts from recorded X-ray diffraction (XRD) patterns focusing on the pseudocubic (100) peak of α -FAPbI₃, the main peaks of the nonperovskite δ -FAPbI₃ phase,⁶¹ and the peak of PbI₂ precursor residue.⁶² Full XRD patterns are displayed in SI, Figure 1. (b) Absorption coefficient spectra (colored solid lines) and Elliott fits to the absorption onsets (dashed black lines) of FAPbI₃ films fabricated via the “DMF-DMSO” (blue), “MACl route” (green), and “sequential” (yellow) solvent-based methods, recorded at 4, 160, and 295 K, respectively. The spectra recorded at different temperatures and for the different fabrication methods are vertically offset for visual clarity, with the black y-axis ticks marking the zero baseline for each successive curve. A direct comparison of the absorption coefficient spectra is presented in SI, Figure 7. (c) Peak features decoupled from the underlying, bulk-like absorption spectrum at 4, 160, and 295 K presented on the same scale. The spectra at different temperatures and for the different fabrication methods are vertically offset for visual clarity, with the black y-axis ticks marking the zero baseline for each successive curve. (d) Spectrally integrated area underneath the absorption peaks shown in (c), given as a percentage of the total area under the absorption coefficient spectrum, used to parametrize the occurrence of quantum confinement, and shown as a function of temperature for the differently fabricated FAPbI₃ films. (The fabrication method legend in (a) also applies to (b), (c), and (d), and the temperature legend in (c) also applies to (b)).

Differences in film fabrication methods will directly influence the crystallization dynamics and structural properties of the resulting perovskite,^{21,32,38–42} which in turn will alter the optoelectronic and photovoltaic performance. We therefore begin by examining the recorded X-ray diffraction (XRD) patterns of the FAPbI₃ films, with Figure 1a showing the relevant region of interest (full XRD patterns displayed in SI, Figure 1). The good coincidence of the main pseudocubic (100) and (200) perovskite peak angles across the three different fabrication methods and their agreement with the expected literature value for α -FAPbI₃,⁶¹ highlight that they indeed yield compositionally similar stoichiometric FAPbI₃ perovskite, without remnant inclusions of MA or Cl. However, differences between these fabrication methods can still be clearly observed in the XRD patterns. The full widths at half-maxima (fwhm) of the main (100) and (200) perovskite peaks (displayed in SI, Figure 2) reflect the longer-range crystalline order and/or lower microstrain in FAPbI₃ films fabricated from the MACl route and sequential deposition method, compared with those for the neat DMF-DMSO route. The scattering intensity of the main α -FAPbI₃ phase is orders of magnitude stronger for the MACl and sequential-deposition processed films, indicating increased texture. The XRD patterns further show a relatively small contribution from impurity phases such as PbI₂ and δ -phase FAPbI₃ (data are plotted on a logarithmic scale) that seem to show little systematic variation between processing routes, with the films resulting from sequential deposition exhibiting the highest scattering intensity for PbI₂

and those derived from the MACl route the highest scattering intensity for the δ -phase FAPbI₃. We note, however, that the presence of such features has been found to correlate poorly with the strength of absorption peak features, likely because the potential structural barriers causing these effects are too thin to be detectable in XRD.⁵⁰ To further interrogate this apparent increase in the texturing of the films using the MACl route and the sequential deposition approach, we also conducted GIWAXS measurements, which we show in SI, Figure 3, along with a detailed comparative analysis of the structural properties and crystallographic quality of these differently fabricated films in SI, section 3. These data confirm an increase in crystallinity and a higher degree of orientation in films fabricated through additive-based or sequential deposition approaches.

We proceeded by probing how the three different fabrication approaches affect the occurrence of intrinsic quantum confinement in FAPbI₃ films. For this purpose, we measured the absorption coefficient spectra at a range of different temperatures from 295 K down to 4 K (displayed in Figure 1b) in order to determine the fraction of the absorption spectrum that exhibits the peak features that have been associated with such confinement in the past.^{50,51} While cryogenic temperatures are less relevant to photovoltaic operation, it has recently been shown that they enhance the sharpness and amplitudes of the absorption features, making them easier to discern and evaluate accurately.^{50,51} To analyze the absorption coefficient spectra, we first fitted the onset with Elliott’s theory,

which takes into account the excitonic contribution and Coulombic enhancement to the absorption spectrum^{63,64} (see dashed lines in Figure 1b). These fits yielded parameters such as the optical bandgap and exciton binding energy (see SI, Figure 8) that are very similar in both value and temperature trends for the films made through the three fabrication routes, further highlighting that these films are compositionally similar. Similarly, room-temperature PL peak energies are found to be identical for all three types of FAPbI₃ films (see SI, Figure 9). As a second step, to determine the contribution to the absorption spectrum arising from quantum confinement, we decoupled the above-bandgap absorption peak features from the underlying, smooth, bulk-like spectrum using the process previously reported.^{50,51} We chose a phenomenological spline baseline connecting all the troughs of the features together and subtracted this baseline from the full absorption spectrum. The resulting decoupled peaks associated with intrinsic quantum confinement are shown in Figure 1c for different FAPbI₃ film fabrication methods and temperatures.^{50,51} As a numerical parameter characterizing the relative prominence of quantum confinement, we evaluated the area between the experimental absorption coefficient spectrum and the spline baseline connecting the troughs (i.e., the integral over the decoupled peak spectra such as those shown in Figure 1c) as a percentage of the overall area under the absorption spectrum. This “spectral area under the peaks” is shown in Figure 1d as a function of temperature for the FAPbI₃ films processed by the three different methods.

Intriguingly, this analysis reveals that the fabrication method has a profound influence on the prominence of the absorption peak features, despite these all being stoichiometrically similar FAPbI₃ films. While FAPbI₃ films fabricated from the neat DMF-DMSO method exhibit very prominent absorption peak features, those features are over an order of magnitude lower in amplitude and hardly discernible for the films fabricated through the MACl and sequential deposition routes, even at very low temperatures down to 4 K (Figure 1c,d). These differences clearly point toward the crystallization process, the experienced strain in the system, and/or small inclusions of δ -phase or one of its polymorphs playing a significant role in the self-assembly of domains causing electronic confinement in the perovskite film. Such variations make sense in the context of quantum confinement in FAPbI₃ having been proposed to be caused by inclusions of thin layers of δ -phase that act as electronic barrier to the α -phase, possibly to achieve periodic strain relief in the system.⁵⁰ Similarly, a range of different hexagonal polytypes have been shown to create peaked absorption features at various energies.⁶⁵ The presence of these peaked absorption features in FAPbI₃ therefore appear to be a direct indicator of crystalline quality. The comparatively uncontrolled crystallization process associated with the neat DMF-DMSO fabrication method is known to result in poorer crystallographic quality of FAPbI₃ films and an instability toward reversion into the δ -phase,^{11,20,21,40,42} and these films exhibit strong absorption peak features. In contrast, the MACl additive provides intermediate-phase directed crystallization, which yields better control over growth dynamics, while the sequential deposition method nucleates α -phase growth, both of which lead to superior crystalline quality, and, as we show here, a significantly lower propensity toward formation of inferred quantum-confined domains.^{55,66} We therefore demonstrate that thin-film nucleation and crystallization control

can regulate and eliminate the quantum confinement experienced in FAPbI₃.

The appearance of domains exhibiting electronic confinement has the potential to hinder charge-carrier extraction in solar cells. We thus proceeded by assessing the extent to which the presence of such absorption features affects the performance of photovoltaic devices incorporating FAPbI₃ absorber layers fabricated using the neat DMF-DMSO, MACl, and sequential deposition routes. Devices were fabricated using a typical n-i-p configuration (FTO/SnO₂/FAPbI₃/PEAI/spiro-OMeTAD/Au). Here, the main difference in PV performance parameters should therefore be associated with the properties of each FAPbI₃ photoabsorber layer. Accordingly, the steady-state short-circuit current density (J_{SC}) of optimized devices can be treated as a parameter to gauge how efficient and unobstructed the charge-carrier motion is throughout the MHP layer. Full details of device fabrication and more detailed comparisons of the performance parameters for these devices are presented in section 7 in the SI. In addition, for each FAPbI₃ film fabrication type, absorber layer thicknesses were optimized for best performance, yielding 340, 440, and 770 nm for the neat DMF-DMSO, MACl, and sequential deposition routes, respectively (see SEM images in SI, section 4, Figures 4–6).⁵⁸ While we acknowledge that generally, increasing the thickness of the perovskite layer will result in increased light absorption and hence, current generation, we note that the devices made with FAPbI₃ films of similar thicknesses, processed with and without the MACl additive, still possessed a substantial difference in their steady-state J_{SC} values (see SI, section 7). As such, we conclude that the thickness variations in the optimized devices do not affect our general conclusions.

A direct comparison of photovoltaic performance parameters for devices incorporating stoichiometric FAPbI₃ films made with the three different fabrication methods is displayed in Figure 2 and SI, Figures 10–13. The PCEs and steady-state J_{SC} values exhibit a notable improvement for FAPbI₃ films fabricated through the MACl route and sequential deposition method compared with the neat DMF-DMSO method. We note that the MACl route and sequential deposition procedure have been shown to result in improved interfacial alignment with the employed transport layers and trap passivation^{67–69} that are likely to be responsible for the slight increase in steady-state open-circuit voltage (V_{OC}) of the corresponding devices we observe here (Figure 2b). However, such improvements would not be expected to also cause a significant enhancement to the charge-carrier extraction capabilities, and yet, devices incorporating films fabricated through the MACl and sequential deposition routes possess a substantially higher steady-state J_{SC} than those made from the neat DMF-DMSO protocol. Instead, these improvements in steady-state J_{SC} with the MACl route and sequential deposition approach appear to be directly correlated with the removal of the absorption peak features for these types of absorber layers we reported above. Such quantum confinement domains thus appear to induce significantly lower stabilized J_{SC} as a clear indication of poor charge-carrier extraction, consistent with the emergence of high-energy potential barriers obstructing transport across the film.

Our analysis suggests that the quantum confinement present in FAPbI₃-rich films heavily depends on the fabrication method and is detrimental to the performance of the associated photovoltaic device. To examine whether these findings hold more generally beyond the investigated

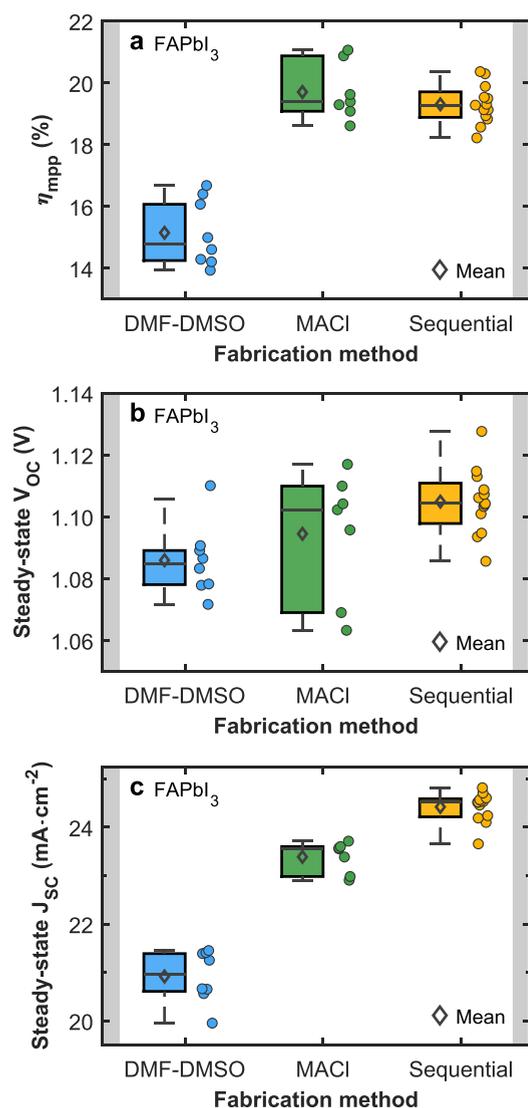


Figure 2. Performance parameters for photovoltaic devices incorporating FAPbI₃ films made from different fabrication methods. Box and scatter plots showing the steady-state photovoltaic parameters for devices based on FAPbI₃ absorber layers fabricated through the “DMF-DMSO” (blue), “MACI route” (green), and “sequential” (yellow) solvent-based methods. (a) Maximum power point tracked power conversion efficiency (η_{mpp}). (b) Steady-state open-circuit voltage (V_{oc}). (c) Steady-state short-circuit current density J_{sc} . The scatter points represent the different device pixels investigated. A comparison of the performance parameters for photovoltaic devices incorporating FAPbI₃ films of different thicknesses fabricated via the “DMF-DMSO” route is displayed in SI, Figure 14.

fabrication methods, we conducted a meta-analysis across a wide range of literature reports. The meta-study was carried out by correlating reported PCE values of FAPbI₃ solar cells with the presence or absence of quantum confinement, as determined from the analysis described and used above of the presence of peak features in the absorption spectra of corresponding films. Selection was effectively limited to devices whose photoactive layer was reported to be FAPbI₃ three-dimensional perovskite thin films, i.e., we excluded any reports where additives or treatments were proven to be fully incorporated into the crystal structure such that they changed

the stoichiometry. As a result, 244 unique publications were included in the meta-study, and a total of 825 device performance reports, providing statistically significant correlation data between PV performance and the presence of quantum confinement (QC). The PV performance data were either the batch-averages across many reported devices, or data corresponding to the champion cell if an average was not reported. Overall, the very large number of devices and published reports on the FAPbI₃ composition (see also Figure 3j) is directly reflective of the historical and continued interest in this thermally stable composition. To assess the correlation between photovoltaic performance and the presence of quantum confinement, we divided the parameters associated with different devices into three unique categories. First, solar cells whose corresponding photoabsorber layer either possessed easily discernible above-bandgap absorption features or features above a certain minimum threshold were labeled “QC present” and amounted to 100 devices. Second, solar cells with no apparent visible features or features below the threshold were labeled “QC absent” and amounted to 302 devices. Finally, when absorption spectra were absent in the publication reporting the PV performance, or were too noisy to allow conclusion of presence or absence of features, this was labeled “QC data unavailable” and amounted to 423 devices. We note that only about half (48.7%) of the reported device performance parameters come with sufficient absorption data. While this still provides us with ample available data (402 device reports) to retrieve statistically significant correlations, it highlights that insufficient attention has been devoted to these absorption features and their relevance to photovoltaic device performance to date. Full details on the nuances of our meta-study can be found in SI, section 8.

The results from our meta-analysis are visualized in a range of different scatter plots in Figure 3 and SI, Figures 15–24. At first sight, it is apparent that PCE values of FAPbI₃ solar cells follow a clear upward trajectory of continuous enhancement of PV properties over time, culminating in the highest certified PCE for a MHP single junction of 25.7%^{3,17} for this composition (Figure 3a). Examining device performance according to the three categories of quantum confinement (present, absent, data unavailable), it also becomes clear that such QC effects have been present or absent since the first realization of working FAPbI₃ PV devices, and that the simple running average of the PCE follows a similar upward trajectory (see Figure 3f). This unrelenting enhancement demonstrates the intense interest invested by the field in this composition and highlights the success of current research in tackling some major hurdles such as reducing defect concentration, improving crystallinity, interface quality, and charge extraction layers. However, more recently, noticeable differences have started to emerge as devices are breaking through the 20% PCE ceiling, reflective of a region where quantum confinement appears to become the decisive factor.

Such evidence for QC features in absorption restricting performance near the Shockley–Queisser limit can be seen in the meta-data in a number of forms. First, Figure 3a shows that since 2019, any meaningful progress in PCE values of devices in the “QC present” category (blue dots) has stalled, with a maximum of only 20.05% attained, compared with 25.06% for the “QC absent” and 25.18% for the “QC data unavailable” categories, suggesting that an intrinsic barrier exists for efficient charge-carrier extraction and PV performance for devices employing films possessing these peculiar QC features. The

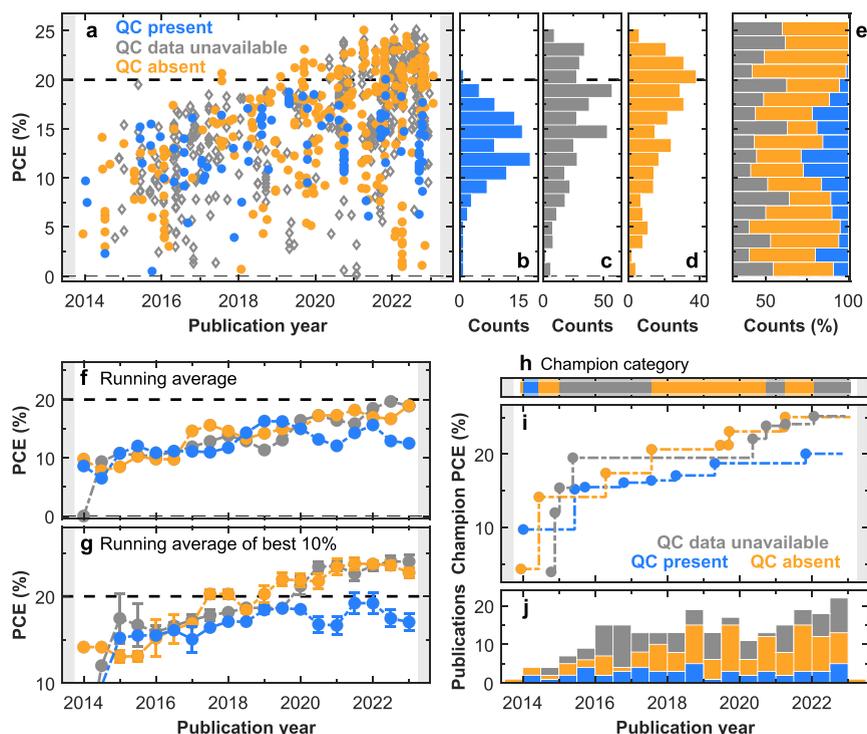


Figure 3. Meta-analysis of photovoltaic device performance and presence of absorbance features for FAPbI₃ thin films extracted from literature. (a) Reported PCE values of single-junction solar cells whose photoabsorber layers compromise stoichiometric bulk FAPbI₃ thin films, plotted as a function of publication year, visualized for three categories of FAPbI₃ films; films with above-bandgap “quantum confinement (QC)” absorption features present (labeled as “QC present”, blue), films for which absorption spectra were unavailable or of insufficient quality or spectral range (labeled as “QC data unavailable”, gray), and films for which absorption data showed no discernible peak features, or features below a certain low threshold (labeled as “QC absent”, orange); see SI, section 8, for full details. (b–d) The total time-integrated device count for each PCE range across the “QC present”, “QC data unavailable”, and “QC absent” categories, respectively. (e) The relative contribution of each category to the available device data for every PCE range, integrated over the years of publication. (f,g) Running average of PCE values recorded for all devices reported in literature, and for the best 10% of devices, respectively, for each category with an averaging window of one year. (h) The time evolution of the absorber film category associated with the highest PCE FAPbI₃ devices. (i) The time evolution of the highest PCE device for each absorber film category. (j) Distribution of the number of unique publications with data on solar cell performance for FAPbI₃ films as a function of publication year divided into the three absorber film categories. The color legend in (a) also applies to b–j).

time-integrated PCE spread in Figure 3b,c,d clearly highlights an abundance of devices in the “QC absent” and “QC data unavailable” categories, with PCE values regularly exceeding the 20% mark, while devices in the “QC present” category very rarely approach that threshold. This is further illustrated in Figures 3h,i, which show that both the “QC absent” and “QC data unavailable” categories also dominate the champion performance since 2014. Finally, Figure 3g provides a temporal evolution of the running average of the best 10% of all devices within each of the three categories showing that even for such averages across the top end of the performance spectrum, the “QC absent” and “QC data unavailable” categories clearly outrun the performance of devices in the “QC present” category. Overall, these meta-data clearly reflect the stagnation in the PV enhancement of the devices in the “QC present” category and the futility of attempts to improve the PCE of a device beyond 20% without attempting to suppress these absorption peak features. Based on this established correlation, a necessary but insufficient condition to obtain devices with efficiencies exceeding ~20% is to ensure the absence of any above-bandgap QC features in the absorption spectrum. We note that, in fact, most of the recent literature-reported attempts to alter the fabrication method of this promising composition with the aim of optimizing its photovoltaic

performance have inadvertently been suppressing these peculiar absorption features.^{38,47,57,70–79} However, the lack of comment on such features in literature reports, and an absence of absorption spectra in over half of the reports we examined, clearly show that little attention has to date been paid to this simple design and validation criterion. Accordingly, we propose that a first point for investigating a new fabrication protocol for FAPbI₃ films to be incorporated into solar cells should be to discern the presence or absence of these peak features in the thin-film absorption spectrum. Such simple assessment can ascertain whether there is a tendency for the fabricated FAPbI₃ films to include electronic barriers that are too thin to be detectable in XRD patterns, but that may still inhibit charge-carrier extraction and whose elimination will thus pave the way for high-performance solar cells.

In conclusion, our work has shown that to realize the highest performing solar cells based on the attractive FAPbI₃ perovskite, quantum confinement needs to be fully eliminated from within the thin-film layer, most likely because it impedes charge-carrier transport and hence restrains the maximum attainable steady-state J_{SC} values. We have conclusively demonstrated this finding through two approaches. First, we have examined a set of stoichiometric FAPbI₃ films with varying degrees of quantum confinement induced by means of

three different solution-based film fabrication processes. Those methods capable of reducing the strain, directing and controlling crystallization, and thus increasing perovskite crystalline quality strongly suppressed the quantum confinement features and clearly enhanced the solar cell performance parameters, in particular, obtainable steady-state J_{SC} values. Second, we have performed a meta-analysis across 244 publications, analyzing 825 occurrences of PCE data from FAPbI₃ solar cells in order to search for correlations with the presence or absence of the quantum confinement features evident from peaks in the matching absorption spectra. Our meta-study reveals that for FAPbI₃ solar cells to break through the 20% PCE ceiling, quantum confinement effects should be absent from the film.

These conclusions clearly highlight simple checks for peaked absorption features as an easy step in the development of new thin-film fabrication procedures aimed at delivering efficient photovoltaic cells based on FAPbI₃. We note that the presence or absence of phase impurities, such as the δ -phase, in XRD patterns is unlikely to be as conclusive because even FAPbI₃ films with strong absorption peak features have at times been found to display no discernible δ -phase peak in XRD.⁵⁰ These electronic barriers may thus offer too few lattice planes to allow sufficiently sharp deflection of X-rays, leading to insufficiently sharp XRD peaks that cannot easily be detected. The alternative criterion we propose here, i.e., an examination of the absorption spectrum, is a simple and experimentally straightforward approach already accessible in the vast majority of research laboratories. This approach should therefore be an easy and powerful means to gauge the effectiveness of any newly developed treatment method for FAPbI₃ thin-film absorber layers. Overall, our findings will accelerate power conversion efficiencies of the most commercially viable MHP on the last stretch toward the maximum theoretical attainable efficiencies for single-junction photovoltaic devices.

■ ASSOCIATED CONTENT

SI Supporting Information

The Supporting Information is available free of charge at <https://pubs.acs.org/doi/10.1021/acsenergylett.3c00656>.

Fabrication method, experimental details, XRD patterns and analysis, cross-sectional scanning electron microscopy images, additional absorption coefficient spectra and details on their fits, additional photovoltaic device performance measurements, and details on the meta-study and subsequent analysis (PDF)

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Notes

The authors declare the following competing financial interest(s): Henry Snaith is cofounder and CSO of Oxford PV ltd, a company commercializing perovskite PV technology.

■ ACKNOWLEDGMENTS

K.A.E. acknowledges the support of the Rank Prize through a Return to Research grant. B.M.G. acknowledges the support of the Plastic Electronics Centre for Doctoral Training. P.H. acknowledges the support from the European Union's Horizon 2020 research and innovation programme under the Marie Skłodowska-Curie grant agreement no. 764787. A.D.W., N.K.K., M.B.J., H.J.S., and L.M.H. acknowledge the Engineering and Physical Sciences Research Council (EPSRC), UK, for financial support, e.g., through grant no. EP/S004947/1. L.M.H. acknowledges support through a Hans Fischer Senior Fellowship from the Technical University of Munich's Institute for Advanced Study, funded by the German Excellence Initiative.

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